ShinDengen

P153FP6SN

Power MOSFETs
60V, 153A, N-channel

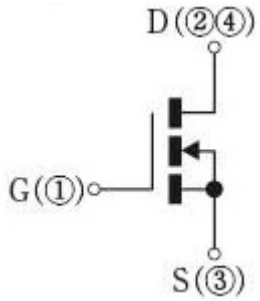
Feature

- N-channel
- SMD
- Large Current
- Low Ron
- 10V Gate Drive
- Low Capacitance
- Pb free terminal
- RoHS:Yes

OUTLINE

Package (House Name): FP
Package (JEITA Code): SC-83 similar

Equivalent circuit



Absolute Maximum Ratings (unless otherwise specified : Tc=25℃)

Item	Symbol	Conditions	Ratings	Unit
Storage temperrature	Tstg		-55 to 175	℃
Channel tempertature	Tch		-55 to 175	℃
Drain-source voltage	V_{DSS}		60	V
Gate-source voltage	V_{GSS}		±20	V
Continuous drain current(DC)	I_D		153	A
Continuous drain current(Peak)	I_{DP}	Pulse width 10μs, duty=1/100	612	A
Total power dissipation	P_T		178	W
Single avalanche current	I_{AS}	Starting Tch=25℃ Tch≦150℃	57	A
Single avalanche energy	E_{AS}	Starting Tch=25℃ Tch≦150℃	355	mJ

※ :See the original Specifications

Electrical Characteristics (unless otherwise specified : Tc=25℃)

Item	Symbol	Conditions	Ratings			Unit
			MIN	TYP	MAX	
Drain-Source breakdown voltage	$V_{(BR)DSS}$	ID=1mA, VGS=0V	60			V
Zero gate voltage drain current	I_{DSS}	VDS=60V, VGS=0V			1	μA
Gate-source leakage current	I_{GSS}	VGS=±20V, VDS=0V			±0.1	μA
Forward transconductance	g_{fs}	ID=76.5A, VDS=10V	27			S
Static drain-source on-state resistance	$R_{DS(ON)}$	ID=76.5A, VGS=10V		0.0024	0.003	Ω
Gate threshold voltage	Vth	ID=1mA, VDS=10V	2	3	4	V
Source-drain diode forward voltage	V_{SD}	IS=153A, VGS=0V			1.5	V
Thermal resistance	Rth(j-c)	Junction to case			0.84	℃/W
Total gate charge	Qg	VDD=48V, VGS=10V, ID=153A		105		nC
Gate to source charge	Qgs	VDD=48V, VGS=10V, ID=153A		31		nC
Gate to drain charge	Qgd	VDD=48V, VGS=10V, ID=153A		51		nC
Input capacitance	Ciss	VDS=25V, VGS=0V, f=1MHz		5850		pF
Reverce transfer capacitnce	Crss	VDS=25V, VGS=0V, f=1MHz		370		pF
Output capacitance	Coss	VDS=25V, VGS=0V, f=1MHz		760		pF
Turn-on delay time	td(on)	ID=76.5A, RL=0.39Ω, VDD=30V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		10		ns
Rise time	tr	ID=76.5A, RL=0.39Ω, VDD=30V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		57		ns
Turn-off delay time	td(off)	ID=76.5A, RL=0.39Ω, VDD=30V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		56		ns
Fall time	tf	ID=76.5A, RL=0.39Ω, VDD=30V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		31		ns
Diode reverse recovery time	trr	IF=153A, VGS=0V, di/dt=100A/μs		45		ns
Diode reverse recovery charge	Qrr	IF=153A, VGS=0V, di/dt=100A/μs		58		nC

※ ：See the original Specifications

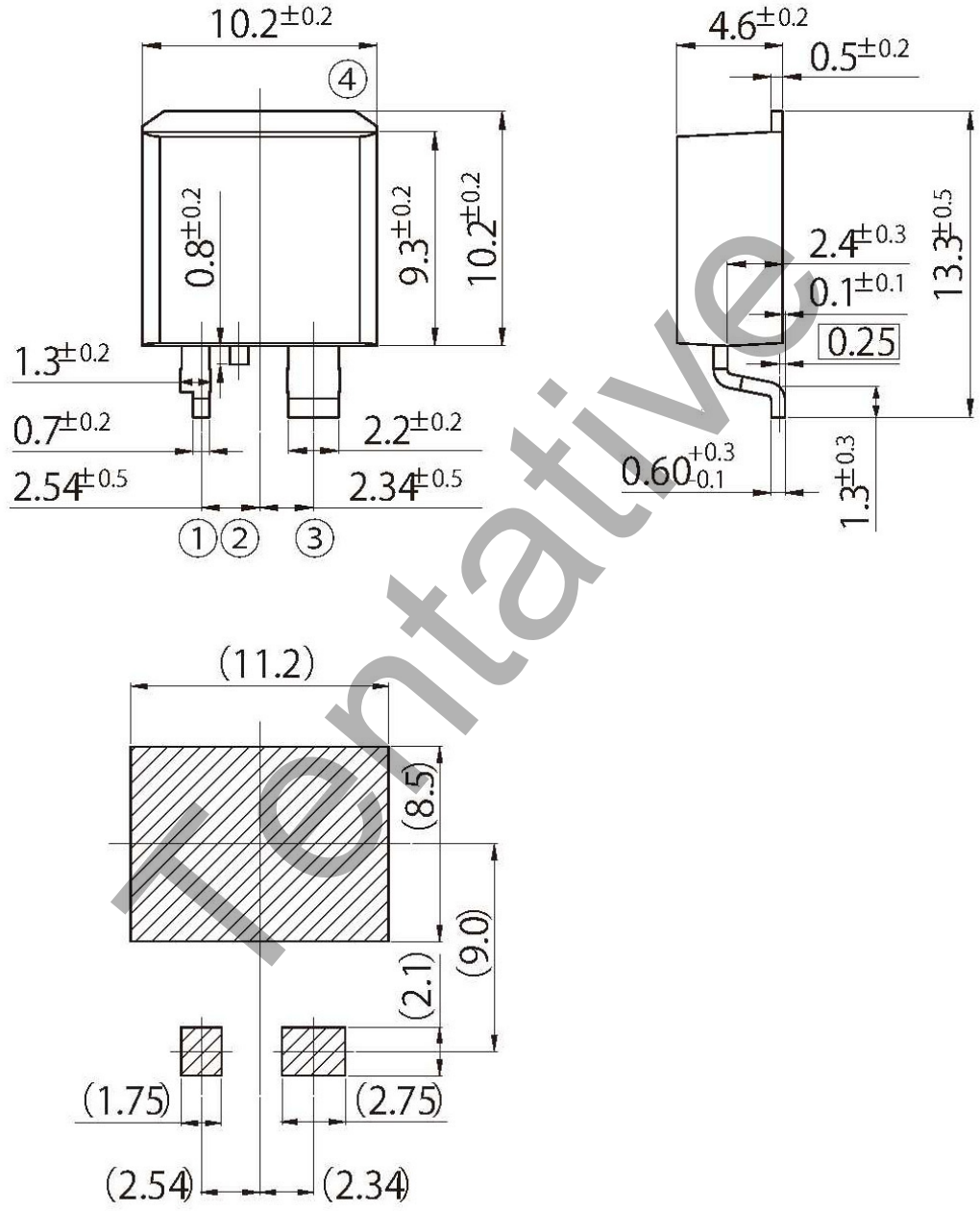
Outline Dimensions

unit:mm

scale: 3/1

H5

JEDEC Code	–
JEITA Code	SC-83 similar
House Name	FP



・量産時には、適正化を図って下さい

・Optimize soldering pad to the board design and soldering condition.

Notes

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